

Provided with
TrueDimensions™
Online access to key probe
parameters for every
individual tip



Type: EBD8-600A | EBD6-400A EBD4-200A | EBD2-100A

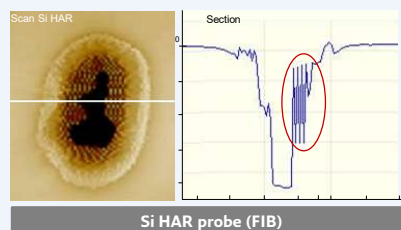
High performance replacement for FIB silicon AFM tips

Extreme aspect ratio EBD AFM tip solutions for extended depth profiling capabilities combine the mechanical stability of a precisely fabricated conical shape and the durability of high-density diamond-like carbon for enhanced and long-lasting tip performance.

Features

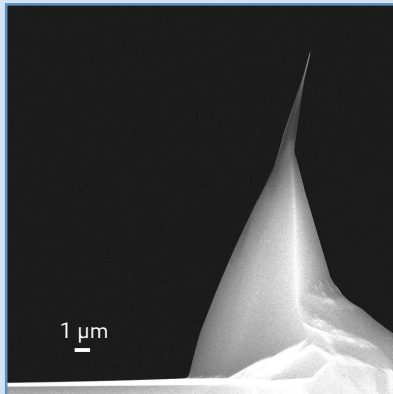
- **Extreme aspect shape.** 2000 nm to 8000 nm long AFM tips with an aspect ratio up to >10 for extended depth profiling.
- **Precise orientation.** Tilt compensated for enhanced feature bottom accessibility and reliable high-resolution inspection of steep structures.
- **Excellent stability.** Conical shape optimized for accurate measurement performance even on sharpest feature edges.
- **Improved throughput.** Outstanding tip material durability for enhanced tip lifetime and reduced cost per measurement.
- **Quality guaranteed.** 100% quality control for every individual tip. Online datasheets including individual dimensional values available 24/7 via QR code.

Application example

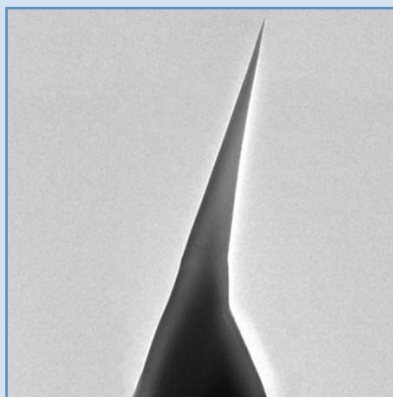


AFM trench recorded with a state-of-the-art Si HAR tip: both the scan (left) and the corresponding profile (right) exhibit considerable dithering on trench edges (red circle). Tapping Mode, 256x256, scan rate 0.2 Hz.

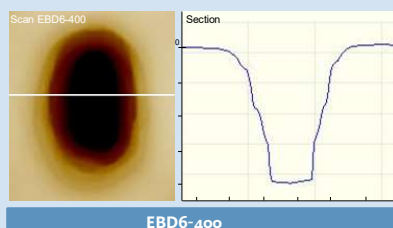
nanotools Extreme Aspect Ratio AFM tips are specially designed and fabricated to overcome inspection accuracy limitations arising from tip-sample sidewall interactions. This effect becomes critical especially on feature discontinuities such as trench edges (see image on the left recorded with an EBD6-400A).



EBD6-400A side view SEM image.



Side view TEM image explicitly revealing the EBD6-400A tip shape uniformity and homogeneity.



Trench scan (left) and the corresponding depth profile (right) measured with an EBD6-400A AFM tip showing accurate feature characteristics.

Tapping Mode, 256x256, scan rate 0.2 Hz.

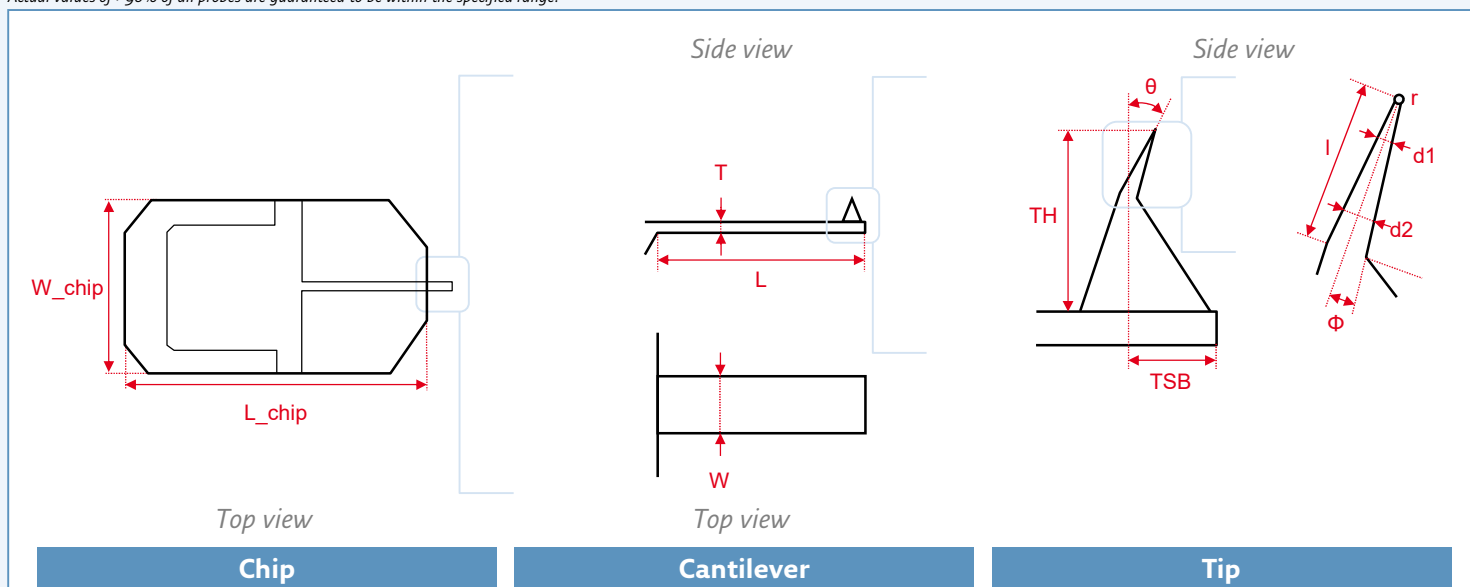
NT_EBD8-600_v0020
NT_EBD6-400_v0030
NT_EBD4-200_v0040
NT_EBD2-100_v0040



Technical specifications

Part number	NT_EBD8-600_v0020	NT_EBD6-400_v0030	NT_EBD4-200_v0040	NT_EBD2-100_v0040
Tip				
Material	HDC/DLC	HDC/DLC	HDC/DLC	HDC/DLC
Length / l	8000 nm (6000-8000 nm)	6000 nm (4000-6000 nm)	4000 nm (3000-4000 nm)	2000 nm (2000-3000 nm)
Width / d ₁	100 nm ^[1] (80-120 nm)	100 nm ^[1] (80-120 nm)	100 nm ^[1] (80-120 nm)	100 nm ^[2] (90-110 nm)
Width / d ₂	600 nm ^[3] (580-620 nm)	400 nm ^[4] (380-420 nm)	200 nm ^[5] (180-220 nm)	n/a
Half cone angle / Φ	<3° (AR>10)	<3° (AR>10)	<3° (AR>10)	<5° (AR>6)
Sharpness / r	<5 nm (<10 nm)	<5 nm (<10 nm)	<5 nm (<10 nm)	<5 nm (<10 nm)
Tilt compensation / θ	12° (±1°)	12° (±1°)	12° (±1°)	12° (±1°)
Total tip height / TH	21 μm (18-23 μm)	19 μm (15-20 μm)	19 μm (15-20 μm)	17 μm (12-18 μm)
Tip set back / TSB	15 μm (5-25 μm)	15 μm (5-25 μm)	15 μm (5-25 μm)	15 μm (5-25 μm)
Cantilever				
Material	Si	Si	Si	Si
Shape	NT-RTESPA	NT-RTESPA	NT-RTESPA	NT-RTESPA
Length / L	120 μm (±5 μm)	120 μm (±5 μm)	120 μm (±5 μm)	120 μm (±5 μm)
Width / W	30 μm (±2 μm)	30 μm (±2 μm)	30 μm (±2 μm)	30 μm (±2 μm)
Thickness / T	4.4 μm (±0.5 μm)	4.4 μm (±0.5 μm)	4.4 μm (±0.5 μm)	4.4 μm (±0.5 μm)
Force constant ^[6] / k	40 N/m (±20 N/m)	40 N/m (±20 N/m)	40 N/m (±20 N/m)	40 N/m (±20 N/m)
Resonance frequency ^[6] / f	320 kHz (±50 kHz)	320 kHz (±50 kHz)	320 kHz (±50 kHz)	320 kHz (±50 kHz)
Tip side coating	none	none	none	none
Back side coating	reflex	reflex	reflex	reflex
Chip				
Length / L _{chip}	3400 μm	3400 μm	3400 μm	3400 μm
Width / W _{chip}	1600 μm	1600 μm	1600 μm	1600 μm
Thickness / T _{chip}	315 μm	315 μm	315 μm	315 μm
Alignment grooves	no	no	no	no

[1] measured at 1000 nm from tip apex | [2] measured at 550 nm from tip apex | [3] measured at 5000 nm from tip apex | [4] measured at 3000 nm from tip apex | [5] measured at 2000 nm from tip apex.
n/a: specification not applicable for this product | [6] Resonance frequency f extracted from LDV measurements; cantilever stiffness k calculated from the (measured) cantilever geometry.
Actual values of >90% of all probes are guaranteed to be within the specified range.



For more information please visit

www.nanotools.com

nanotools GmbH
Reichenbachstraße 33
D-80469 Munich
Phone +49 (0)89 12 11 38-0
info@nanotools.com



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